



S3A/B - S3M/B

#### 3.0A SURFACE MOUNT GLASS PASSIVATED RECTIFIER

#### **Features**

- Glass Passivated Die Construction
- Low Forward Voltage Drop and High Current Capability
- Surge Overload Rating to 100A Peak
- Ideally Suited for Automated Assembly
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SMB/SMC
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 @3
- Polarity: Cathode Band or Cathode Notch
- Weight: SMB 0.093 grams (approximate)

SMC 0.21 grams (approximate)





### Ordering Information\* (Note 4)

| Part Number | Compliance | Case | Packaging        |
|-------------|------------|------|------------------|
| S3xB-13-F   | Standard   | SMB  | 3000/Tape & Reel |
| S3x-13-F    | Standard   | SMC  | 3000/Tape & Reel |

<sup>\*</sup>x = Device type, e.g. S3AB-13-F (SMB package); S3A-13-F (SMC Package).

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



S3x = Product Type Marking Code, ex. S3K (SMC) S3xB = Product Type Marking Code, ex. S3KB (SMB) □!! = Manufacturers' code marking YWW = Date code marking Y = Last digit of year (ex: 13 for 2013) WW = Week code (01 to 53)

1 of 4 S3A/B - S3M/B October 2013 www.diodes.com © Diodes Incorporated Document number: DS16005 Rev. 17 - 2



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

| Characteristic  |                          | Symbol   | S3<br>A/AB | S3<br>B/BB | S3<br>D/DB | S3<br>G/GB | S3<br>J/JB | S3<br>K/KB | S3<br>M/MB | Unit |
|---|--------------------------|--|------------|------------|------------|------------|------------|------------|------------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage              |                          | $egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$ | 50         | 100        | 200        | 400        | 600        | 800        | 1000       | ٧    |
| RMS Reverse Voltage   |                          | $V_{R(RMS)}$   | 30         | 70         | 140        | 280        | 420        | 560        | 700        | V    |
| Average Rectified Output Current  | @ T <sub>T</sub> = +75°C | lo   |            |            |            | 3.0        |            |            |            | Α    |
| Non-Repetitive Peak Forward Surge Current 8.3ms<br>Single Half Sine-Wave Superimposed on Rated Load |                          | I <sub>FSM</sub>                                       |            |            |            | 100        |            |            |            | Α    |

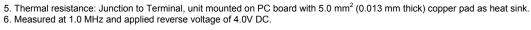
## **Thermal Characteristics**

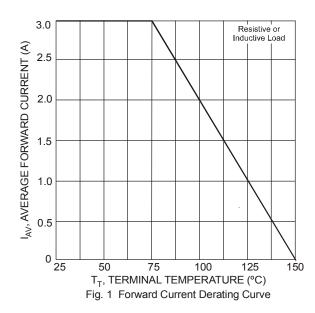
| Characteristic   | Symbol                           | Value       | Unit |
|--|----------------------------------|-------------|------|
| Typical Thermal Resistance Junction to Terminal (Note 5) | $R_{\theta JT}$                  | 10          | °C/W |
| Operating and Storage Temperature Range                  | T <sub>J,</sub> T <sub>STG</sub> | -65 to +150 | °C   |

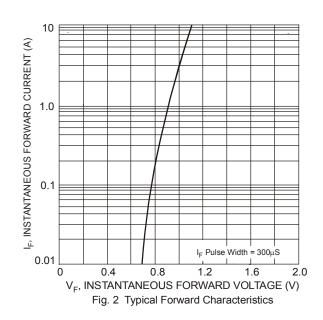
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                    |  | Symbol          | Value     | Unit |
|---|--|-----------------|-----------|------|
| Forward Voltage                                   | $@I_F = 3.0A$  | V <sub>FM</sub> | 1.15      | ٧    |
| Peak Reverse Current at Rated DC Blocking Voltage | @ T <sub>A</sub> = +25°C<br>@ T <sub>A</sub> = +125 °C | I <sub>RM</sub> | 10<br>250 | μA   |
| Typical Total Capacitance (Note 6)                |  | C <sub>T</sub>  | 40        | pF   |

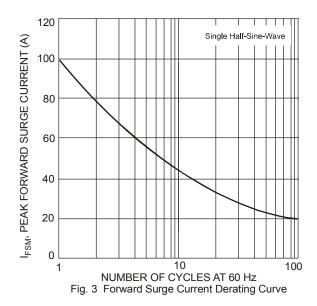
Notes:

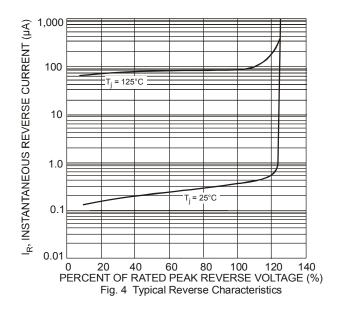






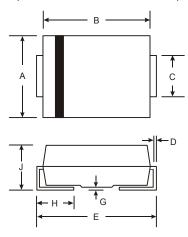






# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

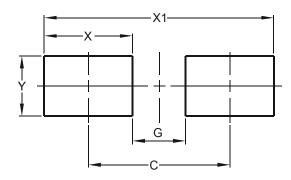


| SMB                  |      |      |  |  |
|----------------------|------|------|--|--|
| Dim                  | Min  | Max  |  |  |
| Α                    | 3.30 | 3.94 |  |  |
| В                    | 4.06 | 4.57 |  |  |
| С                    | 1.96 | 2.21 |  |  |
| D                    | 0.15 | 0.31 |  |  |
| Е                    | 5.00 | 5.59 |  |  |
| G                    | 0.05 | 0.20 |  |  |
| Н                    | 0.76 | 1.52 |  |  |
| J                    | 2.00 | 2.50 |  |  |
| All Dimensions in mm |      |      |  |  |

| SMC                  |      |      |  |  |
|----------------------|------|------|--|--|
| Dim                  | Min  | Max  |  |  |
| Α                    | 5.59 | 6.22 |  |  |
| В                    | 6.60 | 7.11 |  |  |
| C                    | 2.75 | 3.18 |  |  |
| D                    | 0.15 | 0.31 |  |  |
| Е                    | 7.75 | 8.13 |  |  |
| G                    | 0.10 | 0.20 |  |  |
| H                    | 0.76 | 1.52 |  |  |
| J                    | 2.00 | 2.50 |  |  |
| All Dimensions in mm |      |      |  |  |

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| SMB        |                  |  |
|------------|------------------|--|
| Dimensions | Value<br>(in mm) |  |
| С          | 4.30             |  |
| G          | 1.80             |  |
| Х          | 2.50             |  |
| X1         | 6.80             |  |
| Υ          | 2.30             |  |

| SMC        |                  |  |
|------------|------------------|--|
| Dimensions | Value<br>(in mm) |  |
| С          | 6.80             |  |
| G          | 4.40             |  |
| Х          | 2.50             |  |
| X1         | 9.40             |  |
| Υ          | 3.30             |  |



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